# Nch 650V 11A Power MOSFET

V <sub>DSS</sub>	650V
R <sub>DS(on)</sub> (Max.)	0.40Ω
I <sub>D</sub>	±11A
P <sub>D</sub>	124W

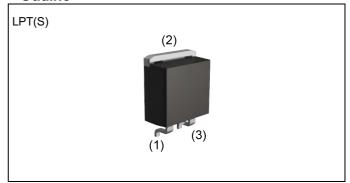
### Features

- 1) Low on-resistance
- 2) Ultra fast switching speed
- 3) Parallel use is easy
- 4) Pb-free plating; RoHS compliant

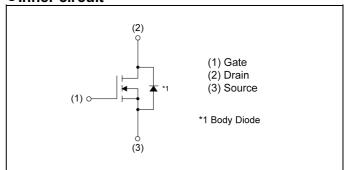
# Application

Switching

### Outline



# •Inner circuit



Packaging specifications

Packing	Embossed Tape
Packing code	TL
Marking	R6511KNJ
Basic ordering unit (pcs)	1000

# ullet Absolute maximum ratings (T<sub>a</sub> = 25°C ,unless otherwise specified)

Parameter	Symbol	Value	Unit	
Drain - Source voltage		V <sub>DSS</sub>	650	V
Continuous drain current (T <sub>c</sub> = 25°C)		I <sub>D</sub> *1	±11	Α
Pulsed drain current		I <sub>DP</sub> *2	±33	Α
Coto Course vallesse	static	V	±20	V
Gate - Source voltage	AC(f>1Hz)	$V_{GSS}$	±30	V
Avalanche current, single pulse		I <sub>AS</sub>	1.8	А
Avalanche energy, single pulse		E <sub>AS</sub> *3	223	mJ
Power dissipation (T <sub>c</sub> = 25°C)	P <sub>D</sub>	124	W	
Junction temperature	T <sub>j</sub>	150	°C	
Operating junction and storage tempera	ature range	T <sub>stg</sub>	-55 to +150	°C

## ●Thermal resistance

Downwortow	Cymah al	Values			1.1:4
Parameter	Symbol	Min.	Тур.	Max.	Unit
Thermal resistance, junction - case	R <sub>thJC</sub> *4	-	-	1.0	°C/W
Thermal resistance, junction - ambient	R <sub>thJA</sub> *5	-	-	80	°C/W
Soldering temperature, wavesoldering for 10s	T <sub>sold</sub>	-	-	265	°C

# ● Electrical characteristics (T<sub>a</sub> = 25°C)

Parameter	Cumb al	Conditions	Values			Unit
- Farameter	Symbol	Conditions	Min.	Тур.	Max.	Offic
Drain - Source breakdown voltage	V <sub>(BR)DSS</sub>	V <sub>GS</sub> = 0V, I <sub>D</sub> = 1mA	650	-	1	V
		$V_{DS} = 650V, V_{GS} = 0V$				
Zero gate voltage drain current	I <sub>DSS</sub>	$T_j = 25^{\circ}C$	-	-	100	μΑ
aram canoni		T <sub>j</sub> = 125°C	-	-	1000	
Gate - Source leakage current	I <sub>GSS</sub>	$V_{GS} = \pm 20V, V_{DS} = 0V$	-	-	±100	nA
Gate threshold voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_{D} = 320 \mu A$	3	-	5	٧
		V <sub>GS</sub> = 10V, I <sub>D</sub> = 3.8A				
Static drain - source on - state resistance	R <sub>DS(on)</sub> *6	$T_j = 25^{\circ}C$	-	0.36	0.40	Ω
		T <sub>j</sub> = 125°C	-	-	-	
Gate resistance	$R_{G}$	f = 1MHz, open drain	-	2.4	-	Ω

# ● Electrical characteristics (T<sub>a</sub> = 25°C)

Davamatar	Cymah al	Conditions	Values			Unit	
Parameter	Symbol	Conditions	Min.	Тур.	Max.	UHIL	
Input capacitance	C <sub>iss</sub>	V <sub>GS</sub> = 0V	-	760	-		
Output capacitance C		V <sub>DS</sub> = 25V	-	710	-	pF	
Reverse transfer capacitance C <sub>rss</sub>		f = 1MHz	-	30	-		
Turn - on delay time	t <sub>d(on)</sub> *6	$V_{DD} \simeq 300V$ , $V_{GS} = 10V$	-	22	-		
Rise time	t <sub>r</sub> *6	I <sub>D</sub> = 5.5A	-	20	-		
Turn - off delay time	t <sub>d(off)</sub> *6	$R_L \simeq 54.9\Omega$	-	45	-	ns	
Fall time	t <sub>f</sub> *6	$R_G = 10\Omega$	-	15	-		

# ● Gate charge characteristics (T<sub>a</sub> = 25°C)

Darameter	Cymahal	Conditions	Values			Lloit
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Total gate charge	$Q_g^{*6}$	V <sub>DD</sub> ≈ 300V	-	22	-	
Gate - Source charge	Q <sub>gs</sub> *6	I <sub>D</sub> = 11A	-	6	1	nC
Gate - Drain charge	${\sf Q_{gd}}^{*6}$	V <sub>GS</sub> = 10V	-	10	-	
Gate plateau voltage	V <sub>(plateau)</sub>	V <sub>DD</sub> ≈ 300V, I <sub>D</sub> = 11A	-	6.7	-	V

<sup>\*1</sup> Limited only by maximum channel temperature allowed.

<sup>\*2</sup> Pw ≤ 10µs, Duty cycle ≤ 1%

<sup>\*3</sup> L $\doteqdot$ 100mH, V<sub>DD</sub>=50V, R<sub>G</sub>=25 $\Omega$ , STARTING T<sub>i</sub>=25 $^{\circ}$ C

<sup>\*4</sup> T<sub>C</sub>=25°C

<sup>\*5</sup> Mounted on an epoxy PCB FR4 (25mm x 27mm x 0.8mm)

<sup>\*6</sup> Pulsed

# ●Body diode electrical characteristics (Source-Drain) (T<sub>a</sub> = 25°C)

Parameter	Symbol	Conditions	Values			Unit	
- Farameter	Symbol	Conditions	Min.	Тур.	Max.	UTIIL	
Source current	I <sub>S</sub> *1	· T <sub>C</sub> = 25°C	1	-	11	Α	
Pulsed source current	l <sub>SP</sub> *2	1C - 23 C	1	-	33	Α	
Source-Drain voltage	V <sub>SD</sub> *6	$V_{GS} = 0V, I_{S} = 11A$	-	-	1.5	V	
Reverse recovery time	t <sub>rr</sub> *6		-	390	-	ns	
Reverse recovery charge	Q <sub>rr</sub> *6	I <sub>S</sub> = 11A di/dt = 100A/μs	-	4.5	-	μC	
Peak reverse recovery current	<sub>rr</sub> *6		-	23	-	Α	

Fig.1 Power Dissipation Derating Curve

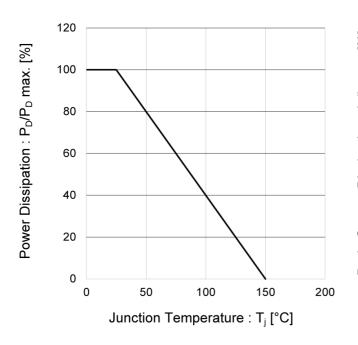


Fig.2 Drain Current Derating Curve

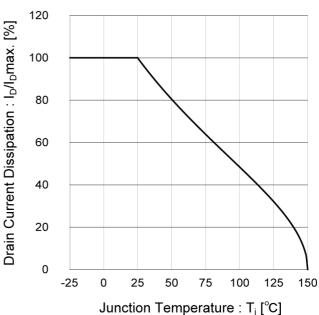


Fig.3 Normalized Transient Thermal Resistance vs. Pulse Width

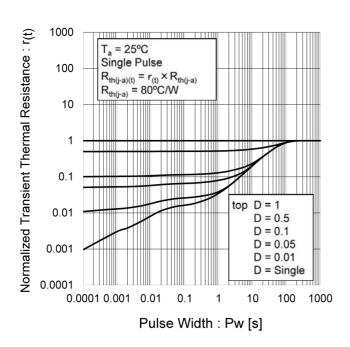
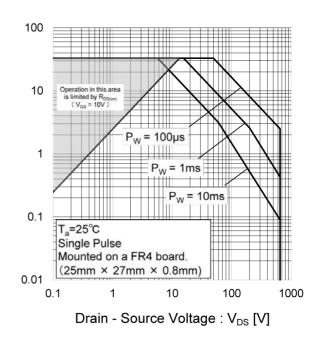


Fig.4 Maximum Safe Operating Area



Drain Current : I<sub>D</sub> [A]

Fig.5 Avalanche Energy Derating
Curve vs. Junction Temperature

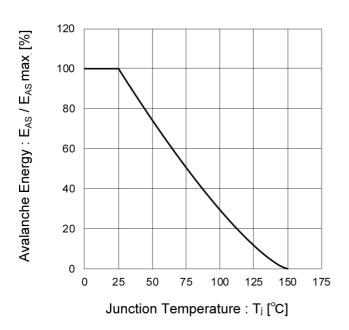


Fig.6 Normalized Breakdown Voltage vs. Junction Temperature

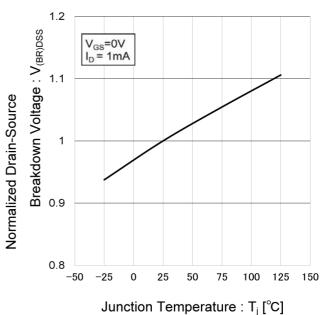


Fig.7 Typical Output Characteristics(I)

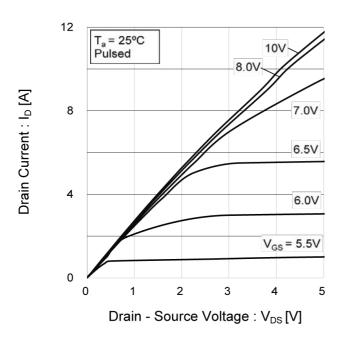
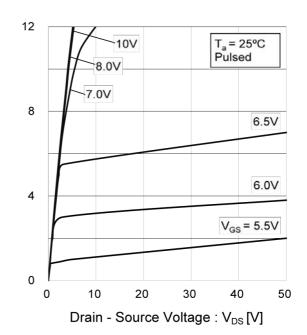


Fig.8 Typical Output Characteristics(II)



Drain Current : I<sub>D</sub> [A]

Fig.9 Typical Transfer Characteristics

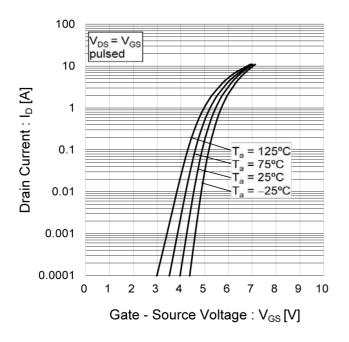


Fig.10 Normalized Gate Threshold .

Voltage vs Junction Temperature

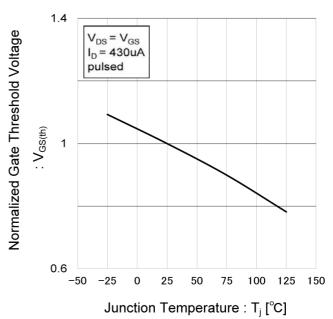


Fig.11 Static Drain - Source On - State Resistance vs. Drain Current

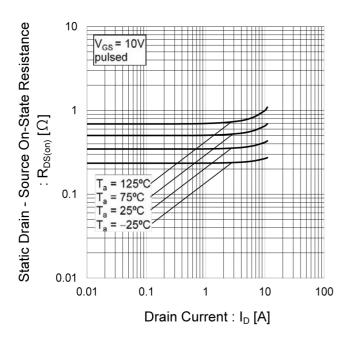


Fig.12 Static Drain - Source On - State Resistance vs. Gate Source Voltage

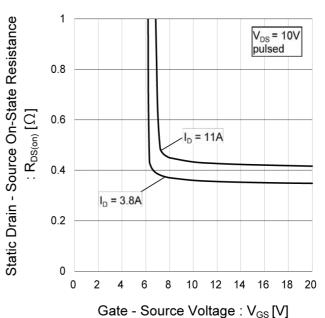


Fig.13 Normalized Static Drain - Source On - State Resistance vs. Junction Temperature

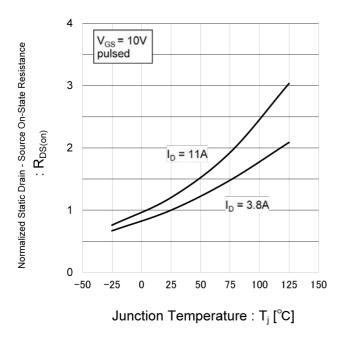
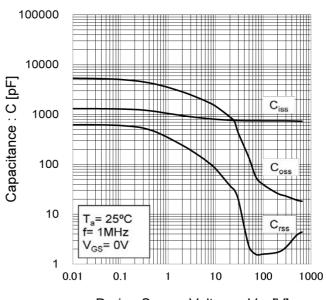


Fig.14 Typical Capacitance vs.

Drain - Source Voltage



Drain - Source Voltage : V<sub>DS</sub> [V]

Fig.15 Switching Characteristics

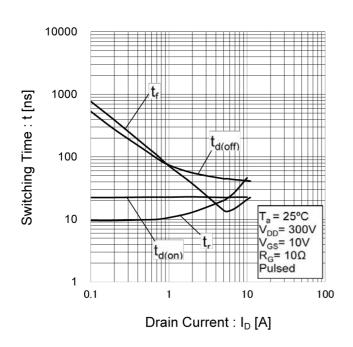
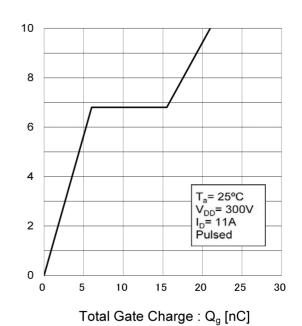


Fig.16 Typical Gate Charge



Gate - Source Voltage : V<sub>GS</sub> [V]

Fig.17 Source Current vs. Source - Drain Voltage

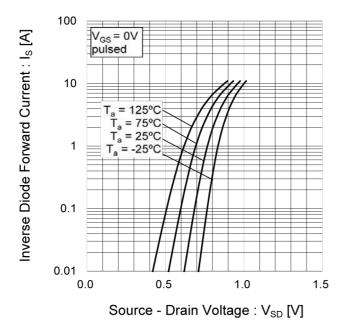
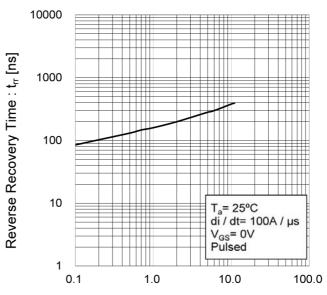


Fig.18 Reverse Recovery Time vs.
Inverse Diode Forward Current



Inve

Inverse Diode Forward Current: I<sub>S</sub> [A]

## Measurement circuits

Fig.1-1 Switching Time Measurement Circuit

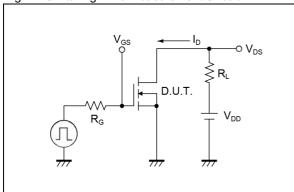


Fig.2-1 Gate Charge Measurement Circuit

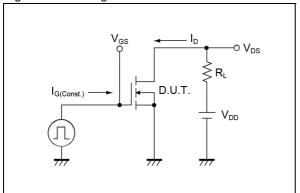


Fig.3-1 Avalanche Measurement Circuit

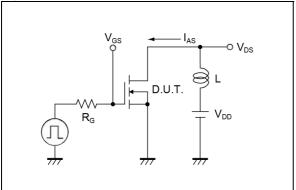


Fig.4-1 trr Measurement Circuit

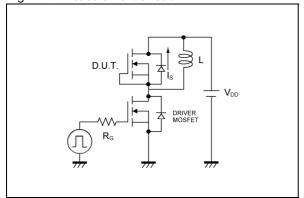


Fig.1-2 Switching Waveforms

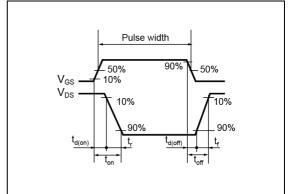


Fig.2-2 Gate Charge Waveform

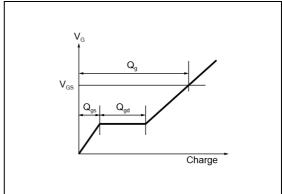


Fig.3-2 Avalanche Waveform

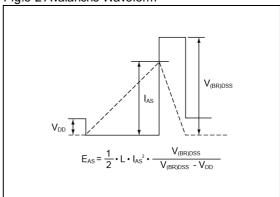
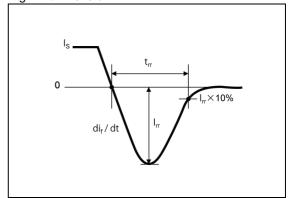
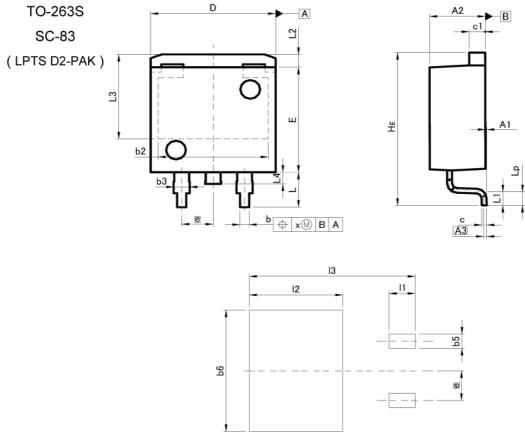


Fig.4-2 trr Waveform



# Dimensions



Pattern of terminal position areas [Not a pattern of soldering pads]

DIM	MILIM	ETERS	INC	HES		
DIM	MIN	MAX	MIN	MAX		
A1	0.00	0.30	0.000	0.012		
A2	4.30	4.70	0.169	0.185		
A3	0.	25	0.0	10		
b	0.68	0.98	0.027	0.039		
b2		90		50		
b3	1.14	1.44	0.045	0.057		
С	0.30	0.60	0.012	0.024		
c1	1.10	1.50	0.043	0.059		
D	9.80	10.40	0.386	0.409		
E	8.80	9.20	0.346	0.362		
е	2.	54	0.1	00		
HE	12.80	13.40	0.504	0.528		
L	2.70	3.30	0.106	0.130		
L1	1.	20	0.047			
L2	1.	10	0.043			
L3	7.	.25 0.285		7.25		85
L4	1.	00	0.0	39		
Lp	0.90	1.50	0.035	0.059		
X	_	0.25	· -	0.010		

 DIM
 MILIMETERS
 INCHES

 MIN
 MAX
 MIN
 MAX

 b5
 1.23
 0.049

 b6
 10.40
 0.409

 I1
 2.10
 0.083

 I2
 7.55
 0.297

 I3
 13.40
 0.528

Dimension in mm/inches



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CLASSIV	CLASSⅢ	CLASSⅢ	CLASSIII

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- 7. De-rate Power Dissipation depending on ambient temperature. When used in sealed area, confirm that it is the use in the range that does not exceed the maximum junction temperature.
- 8. Confirm that operation temperature is within the specified range described in the product specification.
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For details, please refer to ROHM Mounting specification

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This Product is electrostatic sensitive product, which may be damaged due to electrostatic discharge. Please take proper caution in your manufacturing process and storage so that voltage exceeding the Products maximum rating will not be applied to Products. Please take special care under dry condition (e.g. Grounding of human body / equipment / solder iron, isolation from charged objects, setting of lonizer, friction prevention and temperature / humidity control).

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  - [c] the Products are exposed to direct sunshine or condensation
  - [d] the Products are exposed to high Electrostatic
- Even under ROHM recommended storage condition, solderability of products out of recommended storage time period
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  exceeding the recommended storage time period.
- 3. Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.
- 4. Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

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